



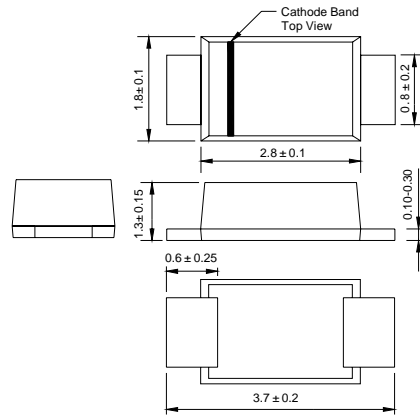
SS32 - SS310

Features

- Metal to silicon rectifiers, majority carrier conduction.
- Low forward voltage drop.
- Easy pick and place.
- High surge current capability.

Schottky Rectifiers

SOD-123FL



Absolute Maximum Ratings* $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value								Units
		32	33	34	35	36	38	39	310	
V_{RRM}	Maximum Repetitive Reverse Voltage	20	30	40	50	60	80	90	100	V
$I_{F(AV)}$	Average Rectified Forward Current, @ $T_A = 75^\circ\text{C}$	3.0								A
I_{FSM}	Non-repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave	100								A
T_{stg}	Storage Temperature Range	-55 to +150								$^\circ\text{C}$
T_J	Operating Junction Temperature	-55 to +150								$^\circ\text{C}$

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics

Symbol	Parameter	Value	Units
P_D	Power Dissipation	2.27	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient *	55	$^\circ\text{C/W}$
$R_{\theta JL}$	Thermal Resistance, Junction to Lead	17	$^\circ\text{C/W}$

*Device mounted on FR-4 PCB 0.55 x 0.55" (14 x 14 mm).

Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Device								Units
		32	33	34	35	36	38	39	310	
V_F	Forward Voltage @ 3.0 A	550		750		850				mV
I_R	Reverse Current @ rated V_R $T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$	0.5								mA
		20		10						mA



Typical Characteristics

Schottky Rectifiers
(continued)

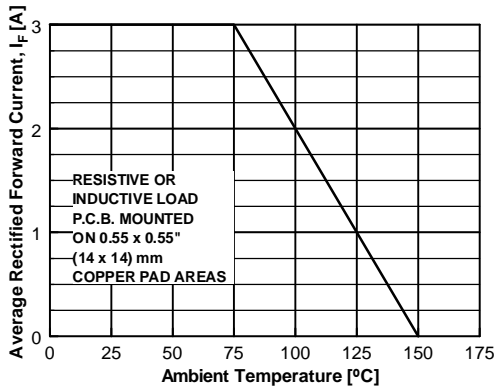


Figure 1. Forward Current Derating Curve

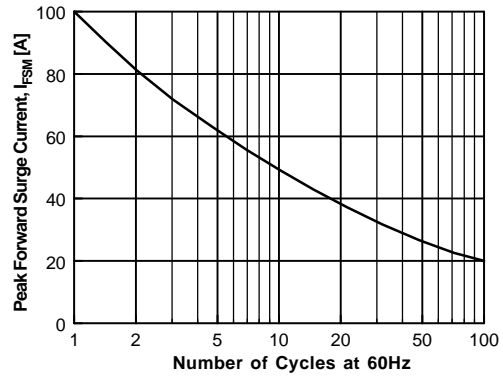


Figure 2. Non-Repetitive Surge Current

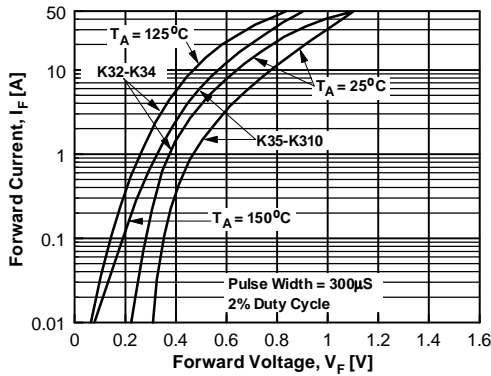


Figure 3. Forward Voltage Characteristics

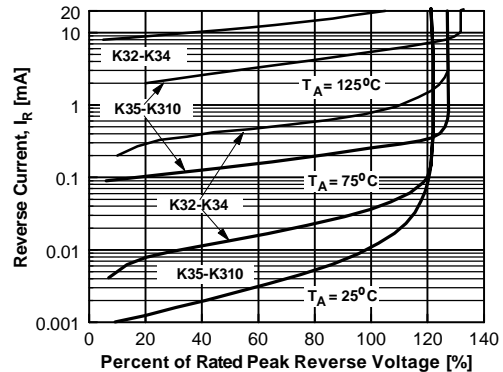


Figure 4. Reverse Current vs Reverse Voltage

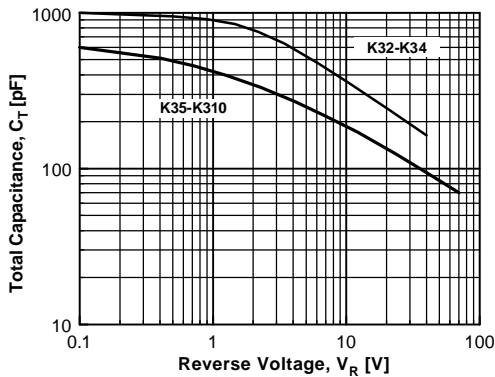


Figure 5. Total Capacitance

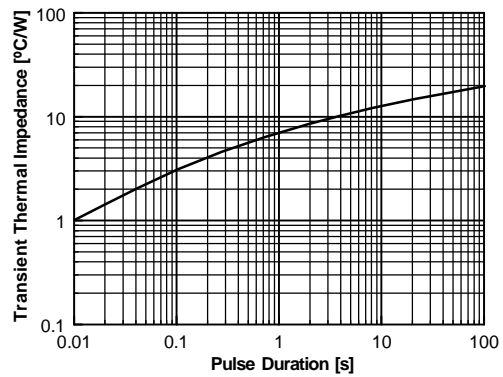


Figure 6. Thermal Impedance Characteristics